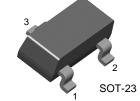


## **KSA812**

### **Low Frequency Amplifier**

- Collector-Base Voltage : V<sub>CBO</sub>= -60V
- Complement to KSC1623



1. Base 2. Emitter 3. Collector

## **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

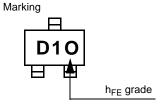
Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
$V_{CEO}$	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	150	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -60V, I <sub>E</sub> =0			-0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = -5V, I <sub>C</sub> =0			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -6V, $I_{C}$ = -1mA	90	200	600	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA		-0.18	-0.3	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE}$ = -6V, $I_{C}$ = -1mA	-0.55	-0.62	-0.65	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE}$ = -6V, $I_{C}$ = -10mA		180		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1MHz		4.5		pF

## $h_{\mbox{\scriptsize FE}}$ Classification

Classification	0	Υ	G	L	
h <sub>FE</sub>	90 ~ 180	135 ~ 270	200 ~ 400	300 ~ 600	



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# **Typical Characteristics**

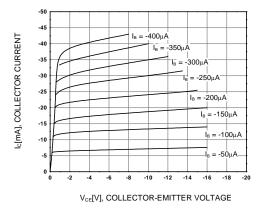


Figure 1. Static Characteristic

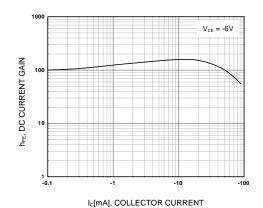


Figure 2. DC current Gain

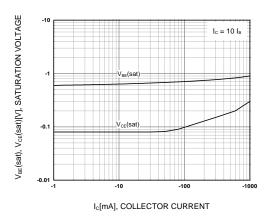


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

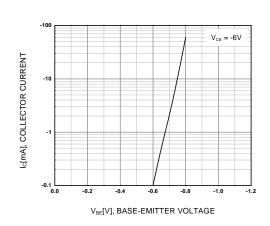


Figure 4. Base-Emitter On Voltage

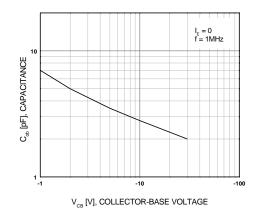


Figure 5. Collector Output Capacitance

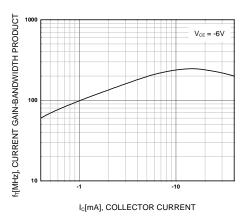
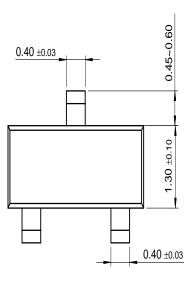


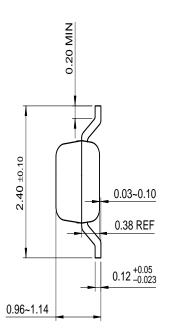
Figure 6. Current Gain Bandwidth Product

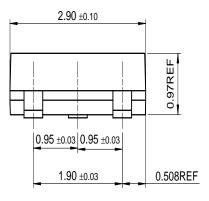
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# **Package Demensions**

# **SOT-23**







Dimensions in Millimeters

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